

HEF4017B

5-stage Johnson decade counter

Rev. 04 — 9 December 2008

Product data sheet

1. General description

The HEF4017B is a 5-stage Johnson decade counter with ten spike-free decoded active HIGH outputs (Q0 to Q9), an active LOW carry output from the most significant flip-flop ($\overline{Q}5-9$), active HIGH and active LOW clock inputs (CP0, $\overline{CP}1$) and an overriding asynchronous master reset input (MR).

The counter is advanced by either a LOW-to-HIGH transition at CP0 while $\overline{CP}1$ is LOW or a HIGH-to-LOW transition at $\overline{CP}1$ while CP0 is HIGH (see [Table 3](#)).

When cascading counters, the $\overline{Q}5-9$ output, which is LOW while the counter is in states 5, 6, 7, 8, and 9, can be used to drive the CP0 input of the next counter. A HIGH on MR resets the counter to zero ($Q0 = \overline{Q}5-9 = \text{HIGH}$; $Q1$ to $Q9 = \text{LOW}$) independent of the clock inputs (CP0, $\overline{CP}1$).

Automatic counter code correction is provided by an internal circuit: following any illegal code the counter returns to a proper counting mode within 11 clock pulses.

Schmitt trigger action makes the clock inputs highly tolerant of slower rise and fall times.

It operates over a recommended V_{DD} power supply range of 3 V to 15 V referenced to V_{SS} (usually ground). Unused inputs must be connected to V_{DD} , V_{SS} , or another input. It is also suitable for use over both the industrial ($-40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$) and automotive ($-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$) temperature ranges.

2. Features

- Automatic counter correction
- Tolerant of slow clock rise and fall times
- Fully static operation
- 5 V, 10 V, and 15 V parametric ratings
- Standardized symmetrical output characteristics
- Operates across the automotive temperature range $-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$
- Complies with JEDEC standard JESD 13-B
- ESD protection:
 - ◆ HBM JESD22-A114E exceeds 2000 V
 - ◆ MM JESD22-A115-A exceeds 200 V

3. Applications

- Industrial and automotive

4. Ordering information

Table 1. Ordering information
All types operate from -40 °C to +125 °C

Type number	Package		Version
	Name	Description	
HEF4017BP	DIP16	plastic dual in-line package; 16-leads (300 mil)	SOT38-4
HEF4017BT	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1

5. Functional diagram

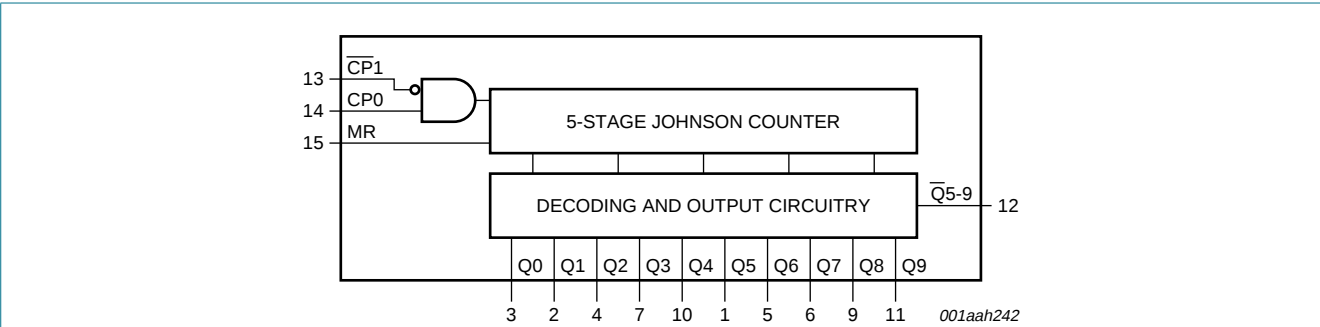


Fig 1. Functional diagram

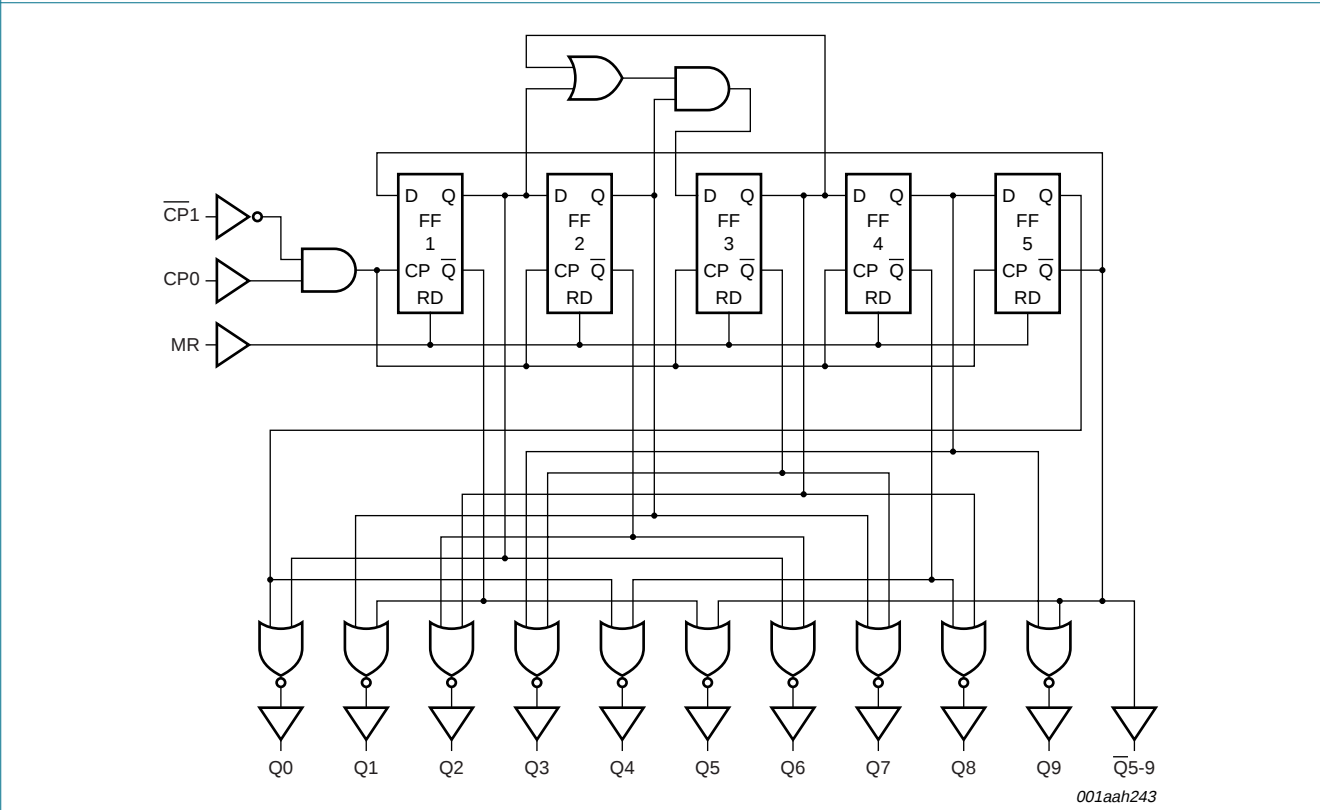


Fig 2. Logic diagram

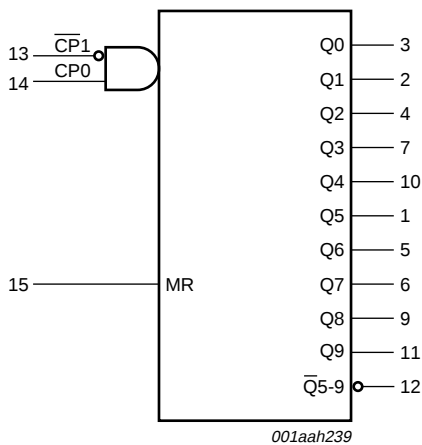


Fig 3. Logic symbol

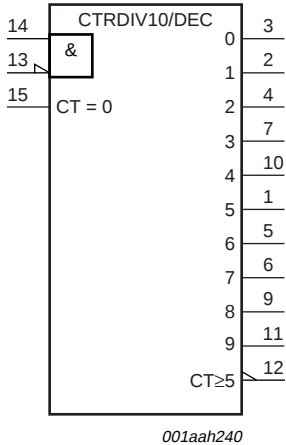


Fig 4. IEE logic symbol

6. Pinning information

6.1 Pinning

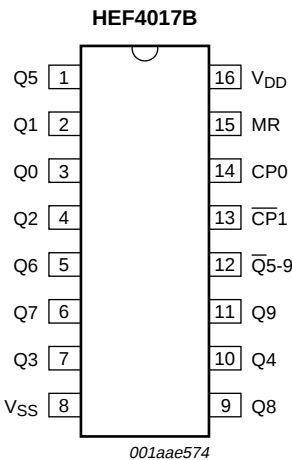


Fig 5. Pin configuration

6.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
Q0 to Q9	3, 2, 4, 7, 10, 1, 5, 6, 9, 11	decoded output
V _{SS}	8	ground supply voltage
Q5-9	12	carry output (active LOW)
CP1	13	clock input (HIGH-to-LOW edge-triggered)

Table 2. Pin description ...continued

Symbol	Pin	Description
CP0	14	clock input (LOW-to-HIGH edge-triggered)
MR	15	master reset input
V _{DD}	16	supply voltage

7. Functional description

Table 3. Function table [1]

MR	CP0	CP1	Operation
H	X	X	$Q0 = \overline{Q5-9} = H$; $Q1$ to $Q9 = L$
L	H	↓	counter advances
L	↑	L	counter advances
L	L	X	no change
L	X	H	no change
L	H	↑	no change
L	↓	L	no change

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care;
↑ = positive-going transition; ↓ = negative-going transition.

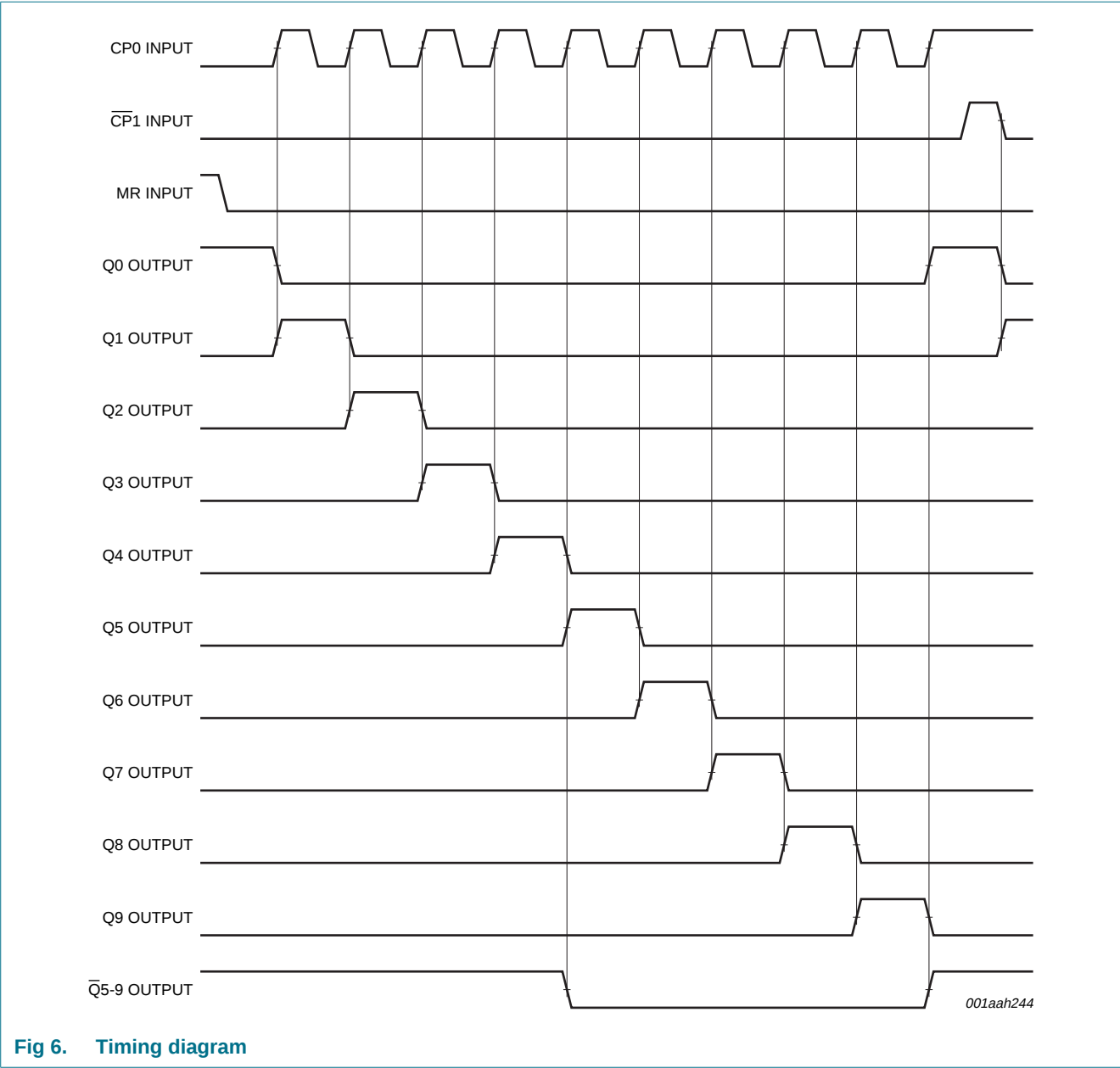


Fig 6. Timing diagram

8. Limiting values

Table 4. Limiting values
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DD}	supply voltage		-0.5	+18	V
I_{IK}	input clamping current	$V_I < 0.5\text{ V}$ or $V_I > V_{DD} + 0.5\text{ V}$	-	± 10	mA
V_I	input voltage		-0.5	$V_{DD} + 0.5$	V
I_{OK}	output clamping current	$V_O < 0.5\text{ V}$ or $V_O > V_{DD} + 0.5\text{ V}$	-	± 10	mA
$I_{I/O}$	input/output current		-	± 10	mA

Table 4. Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
I_{DD}	supply current		-	50	mA
T_{stg}	storage temperature		-65	+150	°C
T_{amb}	ambient temperature		-40	+125	°C
P_{tot}	total power dissipation	$T_{amb} = -40\text{ °C to }+125\text{ °C}$			
		DIP16 package	[1] -	750	mW
		SO16 package	[2] -	500	mW
P	power dissipation	per output	-	100	mW

[1] For DIP16 package: P_{tot} derates linearly with 12 mW/K above 70 °C.[2] For SO16 package: P_{tot} derates linearly with 8 mW/K above 70 °C.

9. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{DD}	supply voltage		3	-	15	V
V_I	input voltage		0	-	V_{DD}	V
T_{amb}	ambient temperature	in free air	-40	-	+125	°C
$\Delta t/\Delta V$	input transition rise and fall rate	$V_{DD} = 5\text{ V}$	-	-	3.75	ns/V
		$V_{DD} = 10\text{ V}$	-	-	0.5	ns/V
		$V_{DD} = 15\text{ V}$	-	-	0.08	ns/V

10. Static characteristics

Table 6. Static characteristics $V_{SS} = 0\text{ V}$; $V_I = V_{SS}$ or V_{DD} unless otherwise specified.

Symbol	Parameter	Conditions	V_{DD}	$T_{amb} = -40\text{ °C}$		$T_{amb} = 25\text{ °C}$		$T_{amb} = 85\text{ °C}$		$T_{amb} = 125\text{ °C}$		Unit
				Min	Max	Min	Max	Min	Max	Min	Max	
V_{IH}	HIGH-level input voltage	$ I_O < 1\text{ }\mu\text{A}$	5 V	3.5	-	3.5	-	3.5	-	3.5	-	V
			10 V	7.0	-	7.0	-	7.0	-	7.0	-	V
			15 V	11.0	-	11.0	-	11.0	-	11.0	-	V
V_{IL}	LOW-level input voltage	$ I_O < 1\text{ }\mu\text{A}$	5 V	-	1.5	-	1.5	-	1.5	-	1.5	V
			10 V	-	3.0	-	3.0	-	3.0	-	3.0	V
			15 V	-	4.0	-	4.0	-	4.0	-	4.0	V
V_{OH}	HIGH-level output voltage	$ I_O < 1\text{ }\mu\text{A}$; $V_I = V_{SS}$ or V_{DD}	5 V	4.95	-	4.95	-	4.95	-	4.95	-	V
			10 V	9.95	-	9.95	-	9.95	-	9.95	-	V
			15 V	14.95	-	14.95	-	14.95	-	14.95	-	V
V_{OL}	LOW-level output voltage	$ I_O < 1\text{ }\mu\text{A}$; $V_I = V_{SS}$ or V_{DD}	5 V	-	0.05	-	0.05	-	0.05	-	0.05	V
			10 V	-	0.05	-	0.05	-	0.05	-	0.05	V
			15 V	-	0.05	-	0.05	-	0.05	-	0.05	V

Table 6. Static characteristics ...continued $V_{SS} = 0\text{ V}$; $V_I = V_{SS}$ or V_{DD} unless otherwise specified.

Symbol	Parameter	Conditions	V_{DD}	$T_{amb} = -40\text{ °C}$		$T_{amb} = 25\text{ °C}$		$T_{amb} = 85\text{ °C}$		$T_{amb} = 125\text{ °C}$		Unit
				Min	Max	Min	Max	Min	Max	Min	Max	
I_{OH}	HIGH-level output current	$V_O = 2.5\text{ V}$	5 V	-1.7	-	-1.4	-	-1.1	-	-1.1	-	mA
		$V_O = 4.6\text{ V}$	5 V	-0.64	-	-0.5	-	-0.36	-	-0.36	-	mA
		$V_O = 9.5\text{ V}$	10 V	-1.6	-	-1.3	-	-0.9	-	-0.9	-	mA
		$V_O = 13.5\text{ V}$	15 V	-4.2	-	-3.4	-	-2.4	-	-2.4	-	mA
I_{OL}	LOW-level output current	$V_O = 0.4\text{ V}$	5 V	0.64	-	0.5	-	0.36	-	0.36	-	mA
		$V_O = 0.5\text{ V}$	10 V	1.6	-	1.3	-	0.9	-	0.9	-	mA
		$V_O = 1.5\text{ V}$	15 V	4.2	-	3.2	-	2.4	-	2.4	-	mA
I_I	input leakage current		15 V	-	± 0.1	-	± 0.1	-	± 1.0	-	± 1.0	μA
I_{DD}	supply current	$I_O = 0\text{ A}$;	5 V	-	5	-	5	-	150	-	150	μA
		$V_I = V_{SS}$ or V_{DD}	10 V	-	10	-	10	-	300	-	300	μA
			15 V	-	20	-	20	-	600	-	600	μA
C_I	input capacitance		-	-	-	-	7.5	-	-	-	-	pF

11. Dynamic characteristics

Table 7. Dynamic characteristics $T_{amb} = 25\text{ °C}$; $V_{SS} = 0\text{ V}$; for test circuit see [Figure 10](#)

Symbol	Parameter	Conditions	V_{DD}	Extrapolation formula ^[1]	Min	Typ	Max	Unit
t_{PHL}	HIGH to LOW propagation delay	CP0, $\overline{CP}1 \rightarrow Q0$ to $Q9$; see Figure 7	5 V	$113\text{ ns} + (0.55\text{ ns/pF}) C_L$	-	140	280	ns
			10 V	$44\text{ ns} + (0.23\text{ ns/pF}) C_L$	-	55	110	ns
			15 V	$32\text{ ns} + (0.16\text{ ns/pF}) C_L$	-	40	80	ns
		CP0, $\overline{CP}1 \rightarrow \overline{Q}5-9$; see Figure 7	5 V	$118\text{ ns} + (0.55\text{ ns/pF}) C_L$	-	145	290	ns
			10 V	$44\text{ ns} + (0.23\text{ ns/pF}) C_L$	-	55	110	ns
			15 V	$32\text{ ns} + (0.16\text{ ns/pF}) C_L$	-	40	80	ns
		MR $\rightarrow Q1$ to $Q9$; see Figure 8	5 V	$88\text{ ns} + (0.55\text{ ns/pF}) C_L$	-	115	230	ns
			10 V	$39\text{ ns} + (0.23\text{ ns/pF}) C_L$	-	50	100	ns
			15 V	$27\text{ ns} + (0.16\text{ ns/pF}) C_L$	-	35	70	ns

Table 7. Dynamic characteristics ...continued $T_{amb} = 25\text{ }^{\circ}\text{C}$; $V_{SS} = 0\text{ V}$; for test circuit see [Figure 10](#)

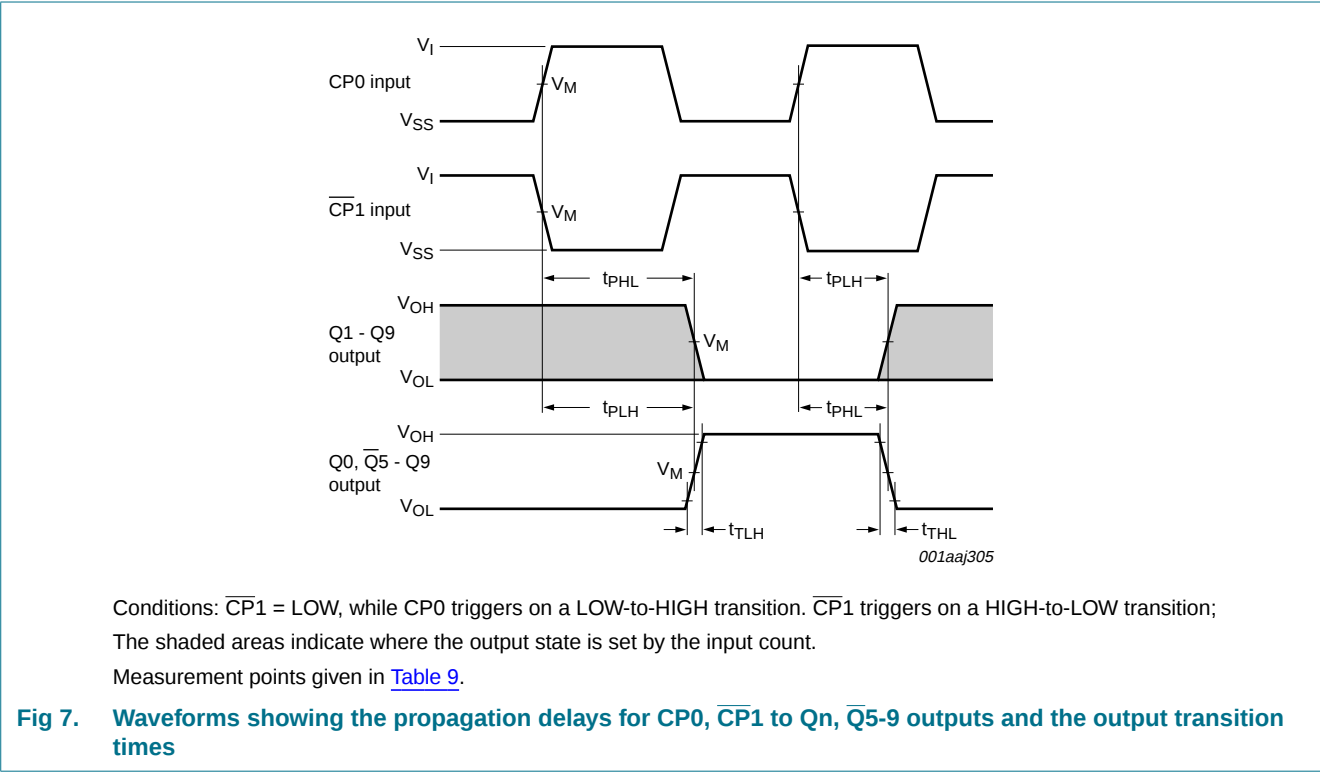
Symbol	Parameter	Conditions	V_{DD}	Extrapolation formula ^[1]	Min	Typ	Max	Unit
t_{PLH}	LOW to HIGH propagation delay	CP0, $\overline{CP1} \rightarrow Q0$ to Q9; see Figure 7	5 V	$98\text{ ns} + (0.55\text{ ns/pF}) C_L$	-	125	250	ns
			10 V	$39\text{ ns} + (0.23\text{ ns/pF}) C_L$	-	50	100	ns
			15 V	$32\text{ ns} + (0.16\text{ ns/pF}) C_L$	-	40	80	ns
		CP0, $\overline{CP1} \rightarrow \overline{Q5-9}$; see Figure 7	5 V	$98\text{ ns} + (0.55\text{ ns/pF}) C_L$	-	125	250	ns
			10 V	$39\text{ ns} + (0.23\text{ ns/pF}) C_L$	-	50	100	ns
			15 V	$32\text{ ns} + (0.16\text{ ns/pF}) C_L$	-	40	80	ns
		MR $\rightarrow \overline{Q5-9}$; see Figure 8	5 V	$83\text{ ns} + (0.55\text{ ns/pF}) C_L$	-	110	220	ns
			10 V	$34\text{ ns} + (0.23\text{ ns/pF}) C_L$	-	45	90	ns
			15 V	$27\text{ ns} + (0.16\text{ ns/pF}) C_L$	-	35	70	ns
		MR $\rightarrow Q0$; see Figure 8	5 V	$103\text{ ns} + (0.55\text{ ns/pF}) C_L$	-	130	260	ns
			10 V	$44\text{ ns} + (0.23\text{ ns/pF}) C_L$	-	55	105	ns
			15 V	$32\text{ ns} + (0.16\text{ ns/pF}) C_L$	-	40	75	ns
t_t	transition time	see Figure 7	5 V	^[2] $10\text{ ns} + (1.00\text{ ns/pF}) C_L$	-	60	120	ns
			10 V	$9\text{ ns} + (0.42\text{ ns/pF}) C_L$	-	30	60	ns
			15 V	$6\text{ ns} + (0.28\text{ ns/pF}) C_L$	-	20	40	ns
t_h	hold time	CP0 $\rightarrow \overline{CP1}$; see Figure 9	5 V		90	45	-	ns
			10 V		40	20	-	ns
			15 V		20	10	-	ns
		$\overline{CP1} \rightarrow CP0$; see Figure 9	5 V		80	40	-	ns
			10 V		40	20	-	ns
			15 V		30	10	-	ns
t_w	pulse width	CP0 input LOW; minimum width; see Figure 8	5 V		80	40	-	ns
			10 V		40	20	-	ns
			15 V		30	15	-	ns
		$\overline{CP1}$ input HIGH; minimum width; see Figure 8	5 V		80	40	-	ns
			10 V		40	20	-	ns
			15 V		30	15	-	ns
		MR input HIGH; minimum width; see Figure 8	5 V		50	25	-	ns
			10 V		30	15	-	ns
			15 V		20	10	-	ns
t_{rec}	recovery time	MR input; see Figure 8	5 V		60	30	-	ns
			10 V		30	15	-	ns
			15 V		20	10	-	ns
f_{max}	maximum frequency	see Figure 8	5 V		6	12	-	MHz
			10 V		12	30	-	MHz
			15 V		15	30	-	MHz

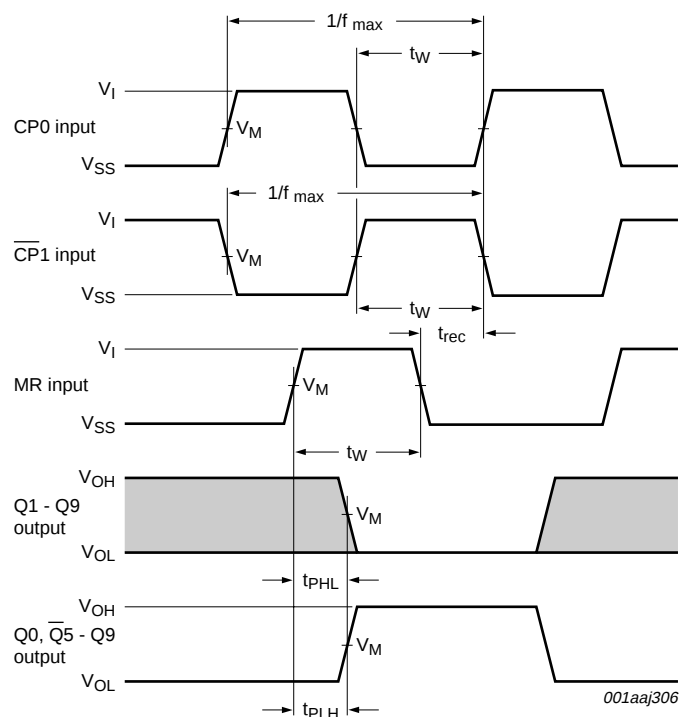
[1] The typical values of the propagation delay and transition times are calculated from the extrapolation formulas shown (C_L in pF).[2] t_t is the same as t_{THL} and t_{TLH} .

Table 8. Dynamic power dissipation P_D
 P_D can be calculated from the formulas shown. $V_{SS} = 0\text{ V}$; $t_r = t_f \leq 20\text{ ns}$; $T_{amb} = 25\text{ }^\circ\text{C}$.

Symbol	Parameter	V _{DD}	Typical formula for P _D (μW)	where:
P _D	dynamic power dissipation	5 V	P _D = 500 × f _i + Σ(f _o × C _L) × V _{DD} ²	f _i = input frequency in MHz;
		10 V	P _D = 2200 × f _i + Σ(f _o × C _L) × V _{DD} ²	f _o = output frequency in MHz;
		15 V	P _D = 6000 × f _i + Σ(f _o × C _L) × V _{DD} ²	C _L = output load capacitance in pF; V _{DD} = supply voltage in V; Σ(C _L × f _o) = sum of the outputs.

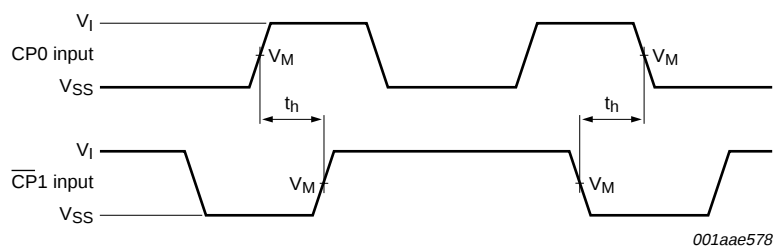
12. Waveforms





Conditions: $\overline{CP1} = \text{LOW}$, while CP0 triggers on a LOW-to-HIGH transition. t_W and t_{rec} are measured when CP0 = HIGH and $\overline{CP1}$ triggers on a HIGH-to-LOW transition;
 The shaded areas indicate where the output state is set by the input count.
 Measurement points given in [Table 9](#).

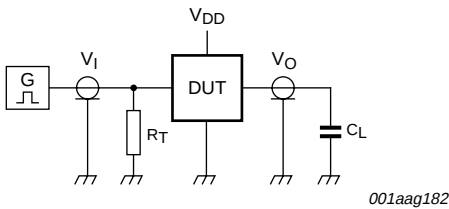
Fig 8. Waveforms showing the minimum pulse width for CP0, $\overline{CP1}$ and MR input; the maximum frequency for CP0 and CP1 input; the recovery time for MR and the MR input to Qn and Q5-9 output propagation delays



Hold times are shown as positive values, but may be specified as negative values;
 Measurement points given in [Table 9](#).

Fig 9. Waveforms showing hold times for CP0 to $\overline{CP1}$ and $\overline{CP1}$ to CP0

Supply voltage	Input	Output
V _{DD}	V _M	V _M
5 V to 15 V	0.5V _{DD}	0.5V _{DD}



Test data is given in [Table 10](#).
Definitions for test circuit:
DUT = Device Under Test;
 C_L = load capacitance including jig and probe capacitance;
 R_T = termination resistance should be equal to the output impedance Z_o of the pulse generator.

Fig 10. Test circuit

Table 10. Test data

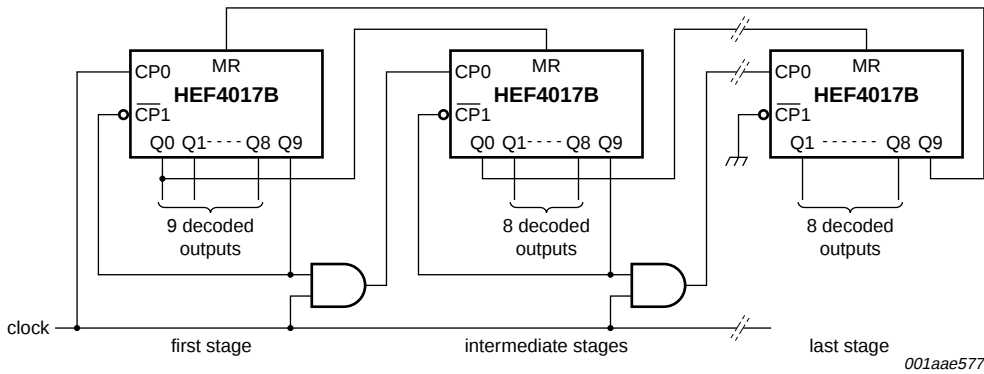
Supply voltage	Input		Load
V_{DD}	V_I	t_r, t_f	C_L
5 V to 15 V	V_{SS} or V_{DD}	≤ 20 ns	50 pF

13. Application information

Some examples of applications for the HEF4017B are:

- Decade counter with decimal decoding
- 1 out of n decoding counter (when cascaded)
- Sequential controller
- Timer

[Figure 11](#) shows a technique for extending the number of decoded output states for the HEF4017B. Decoded outputs are sequential within each stage and from stage to stage, with no dead time (except propagation delay).



Enabling the counter on $\overline{CP1}$ when $CP0$ is HIGH, or on $CP0$ when $\overline{CP1}$ is LOW, causes an extra count.

Fig 11. Counter expansion

14. Package outline

DIP16: plastic dual in-line package; 16 leads (300 mil)

SOT38-4

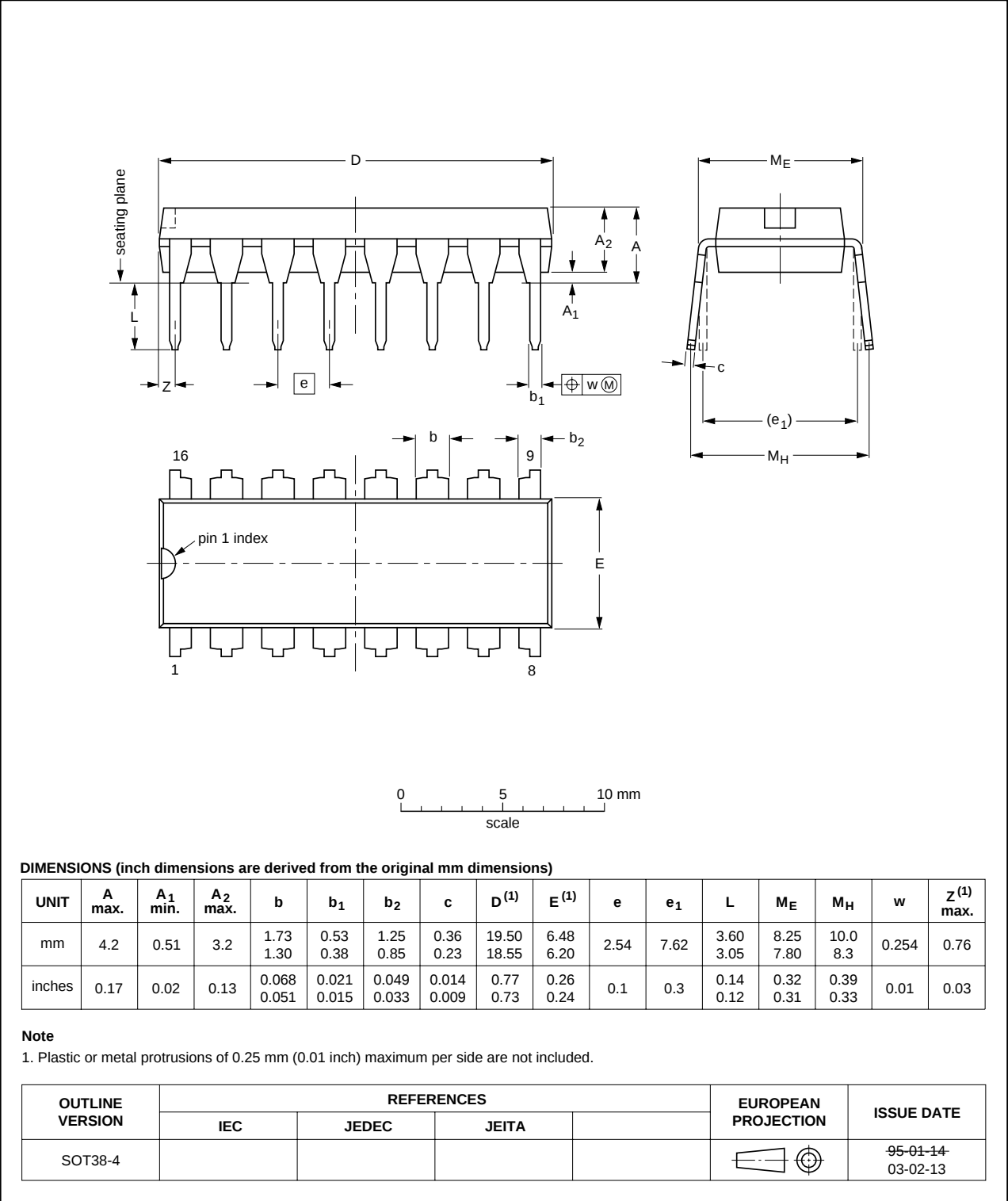


Fig 12. Package outline SOT38-4 (DIP16)

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1

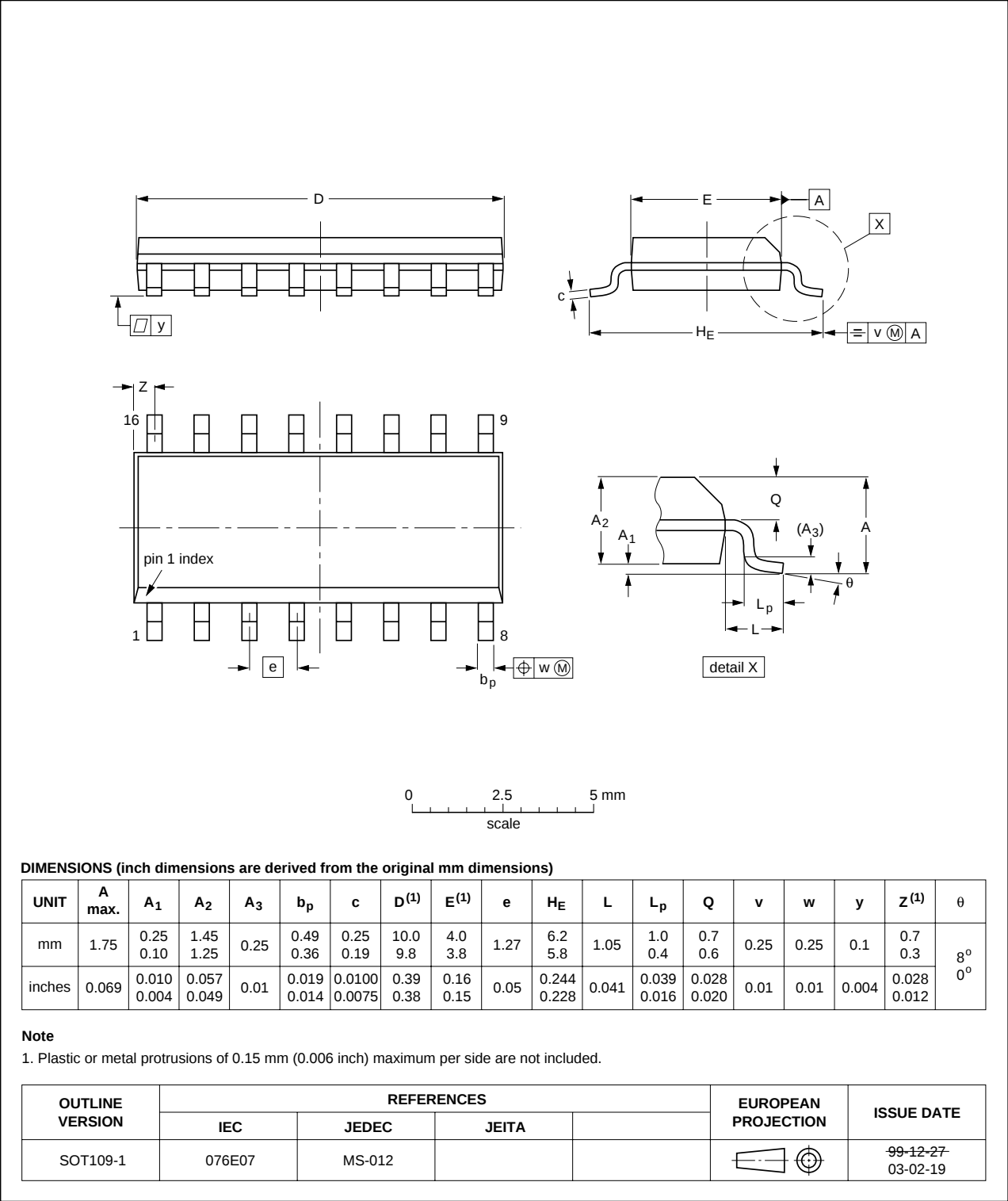


Fig 13. Package outline SOT109-1 (SO16)

15. Abbreviations

Table 11. Abbreviations

Acronym	Description
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model

16. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
HEF4017B_4	20081209	Product data sheet	-	HEF4017B_CNV_3
Modifications:	- The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. - Legal texts have been adapted to the new company name where appropriate. - Rename the pins throughout to be consistent with rest of HEF family. - Increased the maximum ambient temperature to 125 °C throughout. Section 2 "Features" added. - Package version SOT38-1 changed to SOT38-4 in Section 4, and Figure 12. Package SOT74 removed from Section 4. Table 1 "Ordering information" and Table 2 "Pin description" restructured. Figure 3 "Logic symbol" and Figure 4 "IEE logic symbol" added. Section 8 "Limiting values" and Section 10 "Static characteristics" added, taken from the HE4000B Family Specifications data sheet. Section 9 "Recommended operating conditions" added. Table 6 "Static characteristics" restructured. - Values for I_{DD}, I_{OL} and I_{OH} updated in Table 6 "Static characteristics". t_{hold} and t_{RMR} renamed to t_h hold time and t_{rec} recovery time in Table 7 "Dynamic characteristics". and Section 12 "Waveforms". t_{WCPL}, t_{WCPH} and t_{WMRH} renamed to t_W minimum pulse width in Table 7 "Dynamic characteristics". and Section 12 "Waveforms". Figure 7 "Waveforms showing the propagation delays for CP0, CP1 to Qn, Q5-9 outputs and the output transition times" and Figure 10 "Test circuit" added. - Maximum frequency and propagation added to Figure 8 "Waveforms showing the minimum pulse width for CP0, CP1 and MR input; the maximum frequency for CP0 and CP1 input; the recovery time for MR and the MR input to Qn and Q5-9 output propagation delays". Section 14 "Package outline" added.			
HEF4017B_CNV_3	19950101	Product specification	-	HEF4017B_CNV_2
HEF4017B_CNV_2	19950101	Product specification	-	-

17. Legal information

17.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

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